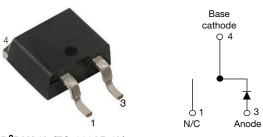
## 1200 V Gen 4 Power Silicon Carbide Schottky Diode, 15 A



D<sup>2</sup>PAK 2L (TO-263AB 2L)

### **LINKS TO ADDITIONAL RESOURCES**



PRIMARY CHARACTERISTICS						
I <sub>F</sub>	15 A					
$V_{R}$	1200 V					
V <sub>F</sub> at I <sub>F</sub> at 25 °C, typ.	1.36 V					
T <sub>J</sub> max.	175 °C					
I <sub>R</sub> at V <sub>R</sub> at 175 °C	200 μΑ					
Q <sub>C</sub> (V <sub>R</sub> = 800 V)	77 nC					
Package	D <sup>2</sup> PAK 2L (TO-263AB 2L)					
Circuit configuration	Single					

#### **FEATURES**

Positive V<sub>F</sub> temperature coefficient for easy paralleling



Virtually no recovery tail and no switching losses

S COMPLIAN

 Minimum creepage and clearance distances are 5.2 mm and 5.4 mm respectively

HALOGEN FREE

- High CTI molding compound provides excellent electrical insulation at relevant working voltages
- Temperature invariant switching behavior
- 175 °C maximum operating junction temperature
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Meets JESD 201 class 1A whisker test
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **DESCRIPTION / APPLICATIONS**

Wide band gap SiC based 1200 V Schottky diode, designed for high performance and ruggedness.

Optimized for extreme high speed hard switching across a wide temperature range. This SiC diode is ideal for applications with high dl/d $_{\rm t}$  such as high efficiency PFC and ultra-high frequency output rectifiers in AC/DC and DC/DC converters.

#### **MECHANICAL DATA**

Case: D<sup>2</sup>PAK 2L (TO-263AB 2L)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Peak repetitive reverse voltage	$V_{RRM}$		1200	V	
Continuous forward current	I <sub>F</sub> <sup>(1)</sup>	T <sub>C</sub> = 150 °C (DC)	15	Α	
Continuous forward current	I <sub>F</sub> <sup>(2)</sup>	T <sub>C</sub> = 137 °C (DC)	15	Α	
DC blocking voltage	$V_{DC}$		1200	V	
Repetitive peak forward current	I <sub>FRM</sub>	$T_C$ = 25 °C, f = 50 Hz, square wave, DC = 25 %	58	A	
Non-venetitive need forward average average	I <sub>FSM</sub>	$T_C = 25$ °C, $t_p = 10$ ms, half sine wave	75		
Non-repetitive peak forward surge current		$T_C = 110$ °C, $t_p = 10$ ms, half sine wave	53	Α	
	P <sub>tot</sub> (1)	T <sub>C</sub> = 25 °C	167	- w - w	
Dower discipation		T <sub>C</sub> = 110 °C	72		
Power dissipation	P <sub>tot</sub> (2)	T <sub>C</sub> = 25 °C	111		
		T <sub>C</sub> = 110 °C	48		
121 -1 -	∫i <sup>2</sup> dt	T <sub>C</sub> = 25 °C	28.1	• • •	
I <sup>2</sup> t value	Ji at	T <sub>C</sub> = 110 °C	13.1	A <sup>2</sup> s	
Operating junction and storage temperatures	T <sub>J</sub> <sup>(3)</sup> , T <sub>Stq</sub>		-55 to +175	°C	

#### **Notes**

- (1) Based on typical Rth
- (2) Based on maximum Rth
- (3) The heat generated must be less than the thermal conductivity from junction-to-ambient: dPp/dTJ < 1/ReJA



<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
		I <sub>F</sub> = 15 A	-	1.36	1.5		
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 15 A, T <sub>J</sub> = 150 °C	-	1.75	2.15	V	
		I <sub>F</sub> = 15 A, T <sub>J</sub> = 175 °C	-	1.88	-		
	I <sub>R</sub>	$V_R = V_R$ rated	-	6.6	100	μΑ	
Reverse leakage current		V <sub>R</sub> = V <sub>R</sub> rated, T <sub>J</sub> = 150 °C	-	93	650		
		V <sub>R</sub> = V <sub>R</sub> rated, T <sub>J</sub> = 175 °C	-	200	-		
Total capacitance	С	V <sub>R</sub> = 1 V, f = 1 MHz	-	889	-	pF	
		V <sub>R</sub> = 800 V, f = 1 MHz	-	53	-	PΓ	
Total capacitive charge	Q <sub>C</sub>	V <sub>R</sub> = 800 V, f = 1 MHz	-	77	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS (T <sub>A</sub> = 25 °C unless otherwise specified)							
PARAMETER	ETER SYMBOL TEST CONDITIONS MIN. TYP. MAX. UNITS						
Thermal resistance, junction to case	R <sub>thJC</sub>		-	0.9	1.35	°C/W	
Marking device	4C15ET12S						

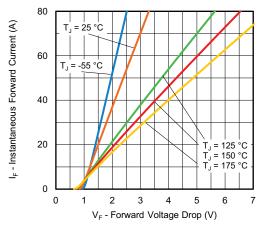


Fig. 1 - Typical Forward Voltage Drop Characteristics

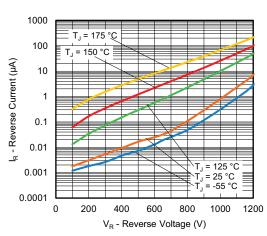


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

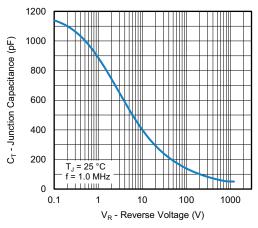


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

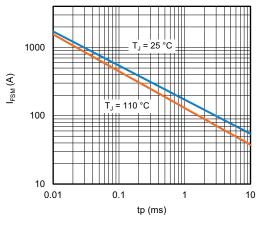


Fig. 4 - Non-Repetitive Peak Forward Surge Current vs. Pulse Duration (Square Wave)

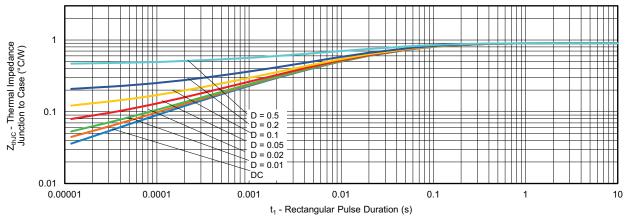


Fig. 5 - Typical Thermal Impedance  $Z_{thJC}$  Characteristics

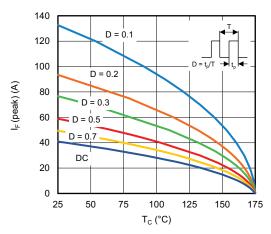


Fig. 6 - Peak Forward Current vs. Maximum Allowable Case Temperature

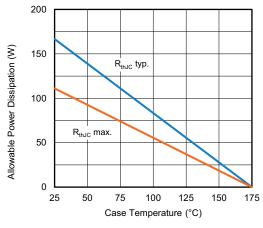


Fig. 7 - Forward Power Loss Characteristics

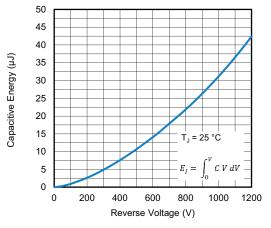


Fig. 8 - Typical Capacitive Energy vs. Reverse Voltage

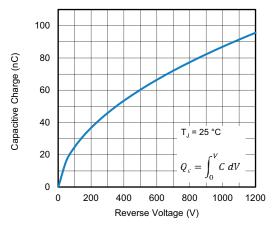
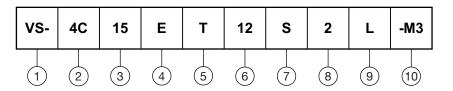


Fig. 9 - Typical Capacitive Charge vs. Reverse Voltage



### **ORDERING INFORMATION TABLE**

**Device code** 



Vishay Semiconductors product

2 - 4C = SiC diode, generation 4

3 - Current rating (15 = 15 A)

4 - E = single diode

5 - T = D<sup>2</sup>PAK package

6 - Voltage rating: (12 = 1200 V)

7 - S = surface mountable

L = tape and reel (left oriented)

10 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

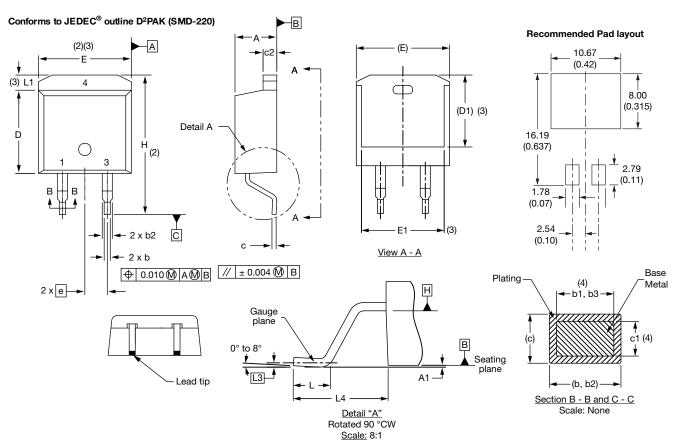
ORDERING INFORMATION						
PREFERRED P/N	UNIT WEIGHT	BASE QUANTITY	PACKAGING DESCRIPTION			
VS-4C15ET12S2L-M3	2 g	800 per reel	13" diameter reel			

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?96683			
Part marking information	www.vishay.com/doc?96693			
Packaging information	www.vishay.com/doc?95032			



# **D<sup>2</sup>PAK 2L (TO-263AB 2L)**

### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIM	ETERS	INC	NOTES	
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIMETERS		INCHES		NOTES
STWIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
Е	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

INICHES

NAUL LINAETEDO

### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



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